

UTC D882SS NPN EPITAXIAL SILICON TRANSISTOR

MEDIUM POWER LOW VOLTAGE
TRANSISTOR

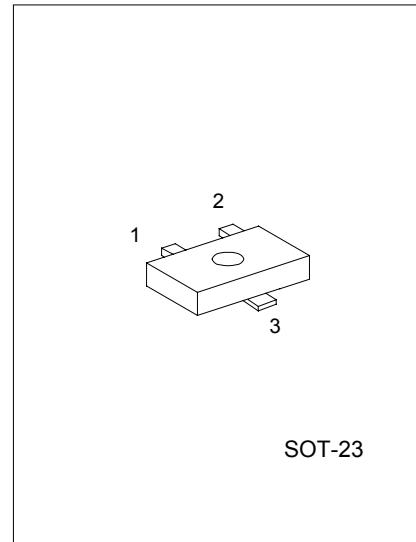
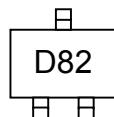
FEATURES

- *High current output up to 3A
- *Low saturation voltage
- *Complement to B772SS

APPLICATIONS

- * Audio power amplifier
- * DC-DC convertor
- * Voltage regulator

MARKING



1: Emitter 2: Base 3: Collector

ABSOLUTE MAXIMUM RATINGS (Ta=25°C ,unless otherwise specified)

| PARAMETERS | SYMBOL | RATING | UNIT |
|--|------------------|------------|------|
| Collector-base voltage | V _{CBO} | 40 | V |
| Collector-emitter voltage | V _{CEO} | 30 | V |
| Emitter-base voltage | V _{EBO} | 5 | V |
| Collector dissipation(T _c =25°C) | P _c | 10 | W |
| Collector dissipation(T _a =25°C) | P _c | 1 | W |
| Collector current(DC) | I _c | 3 | A |
| Collector current(PULSE) | I _c | 7 | A |
| Base current | I _b | 0.6 | A |
| Junction Temperature | T _j | 150 | °C |
| Storage Temperature | T _{STG} | -55 ~ +150 | °C |

ELECTRICAL CHARACTERISTICS(T_a=25°C,unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--------------------------------------|--------------------------------------|--|-----------|------------|------|------|
| Collector cut-off current | I _{cbo} | V _{CB} =30V,I _e =0 | | | 1000 | nA |
| Emitter cut-off current | I _{ebo} | V _{EB} =3V,I _c =0 | | | 1000 | nA |
| DC current gain(note 1) | h _{FE1} h _{FE2} | V _{ce} =2V,I _c =20mA V _{ce} =2V,I _c =1A | 30 100 | 200 150 | 400 | |
| Collector-emitter saturation voltage | V _{ce(sat)} | I _c =2A,I _b =0.2A | | 0.3 | 0.5 | V |
| Base-emitter saturation voltage | V _{be(sat)} | I _c =2A,I _b =0.2A | | 1.0 | 2.0 | V |
| Current gain bandwidth product | f _r | V _{ce} =5V,I _c =0.1A | | 80 | | MHz |
| Output capacitance | C _{ob} | V _{CB} =10V,I _e =0,f=1MHz | | 45 | | pF |

Note 1:Pulse test:PW<300μs,Duty Cycle<2%

UTC UNISONIC TECHNOLOGIES CO. LTD

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QW-R206-018,A

UTC D882SS NPN EPITAXIAL SILICON TRANSISTOR

CLASSIFICATION OF hFE2

| RANK | Q | P | E |
|-------|---------|---------|---------|
| RANGE | 100-200 | 160-320 | 200-400 |

TYPICAL PARAMETERS PERFORMANCE

Fig.1 Static characteristics

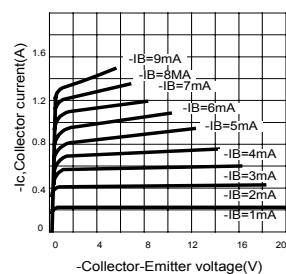


Fig.2 Derating curve of safe operating areas

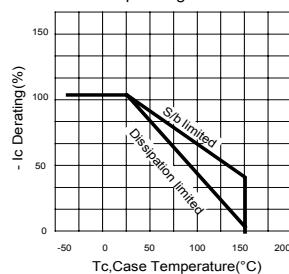


Fig.3 Power Derating

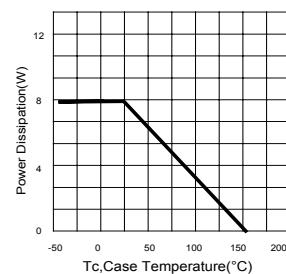


Fig.4 Collector Output capacitance

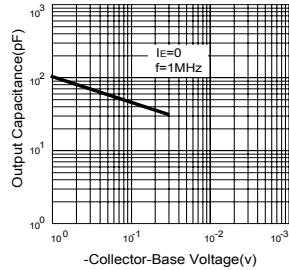


Fig.5 Current gain-bandwidth product

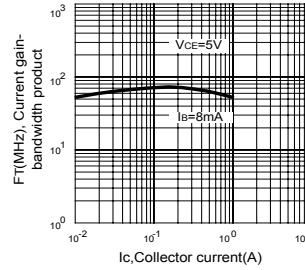


Fig.6 Safe operating area

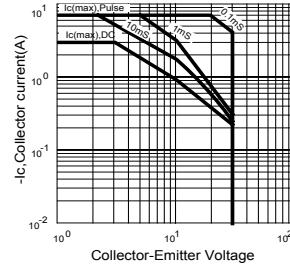


Fig.7 DC current gain

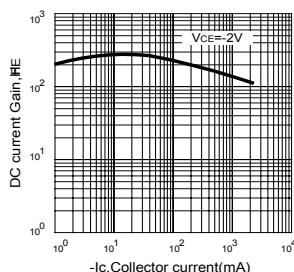


Fig.8 Saturation Voltage

